

L Number	Hits	Search Text	DB	Time stamp
-	34	(single SAME crystal SAME structure) and razor	USPAT; US-PGPUB; EPO; JPO	2004/06/17 17:58
-	2493	(single SAME crystal SAME structure) and silicon and cut\$	USPAT; US-PGPUB; EPO; JPO	2002/05/01 14:02
-	471	razor and guard and skin	USPAT; US-PGPUB; EPO; JPO	2002/04/29 15:42
-	0	((single SAME crystal SAME structure) and silicon and cut\$) and (razor and guard and skin)	USPAT; US-PGPUB; EPO; JPO	2002/04/29 15:42
-	9	"4534827"	USPAT	2002/04/29 16:19
-	12	"5048191"	USPAT	2002/04/29 16:21
-	7	"5018274"	USPAT	2002/04/29 16:21
-	115733	chemical ADJ "3" etching	USPAT	2002/05/01 13:58
-	53591	process and wafer and (crystal ADJ "3" material)	USPAT	2002/05/01 14:02
-	32454	(chemical ADJ "3" etching) and (process and wafer and (crystal ADJ "3" material))	USPAT; US-PGPUB; EPO; JPO	2002/05/01 14:06
-	27930	(chemical ADJ "3" etching) and (process and wafer and (crystal ADJ "3" material)) and silicon	USPAT; US-PGPUB; EPO; JPO	2002/05/01 14:09
-	0	((chemical ADJ "3" etching) and (process and wafer and (crystal ADJ "3" material)) and silicon) and ctystallographic SAME structure	USPAT; US-PGPUB; EPO; JPO	2002/05/01 14:09
-	472	((chemical ADJ "3" etching) and (process and wafer and (crystal ADJ "3" material)) and silicon) and crystallographic SAME structure	USPAT; US-PGPUB; EPO; JPO	2002/05/01 14:10
-	1	"4807360".PN.	USPAT	2002/10/03 10:03
-	1	"4702004".PN.	USPAT	2002/10/03 10:03
-	1	"4663843".PN.	USPAT	2002/10/03 10:03
-	1	"4389773".PN.	USPAT	2002/10/03 10:04
-	1	"4200976".PN.	USPAT	2002/10/03 10:04
-	1	"4056992".PN.	USPAT	2002/10/03 10:05
-	1	"4056992".PN.	USPAT	2002/10/03 10:06
-	1	"4011071".PN.	USPAT	2002/10/03 10:06
-	1	"3953186".PN.	USPAT	2002/10/03 10:06
-	1	"4011071".PN.	USPAT	2002/10/03 10:06
-	1	"3953186".PN.	USPAT	2002/10/03 10:06
-	1	"3831466".PN.	USPAT	2002/10/03 10:06
-	1	"3953186".PN.	USPAT	2002/10/03 10:06
-	1	"3911579".PN.	USPAT	2002/10/03 10:06
-	1	"3911579".PN.	USPAT	2002/10/03 10:07
-	1	"3831466".PN.	USPAT	2002/10/03 10:07
-	1	"3829969".PN.	USPAT	2002/10/03 10:07
-	1	"3805387".PN.	USPAT	2002/10/03 10:07
-	1	"3543402".PN.	USPAT	2002/10/03 10:07
-	1	"3263328".PN.	USPAT	2002/10/03 10:07
-	1	"3263328".PN.	USPAT	2002/10/03 10:07
-	1	"2614321".PN.	USPAT	2002/10/03 10:08
-	1	"1920711".PN.	USPAT	2002/10/03 10:08
-	104	(30/346.54).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2002/10/03 11:23
-	36	(30/346.54).CCLS.	USOCR	2002/10/03 11:24
-	122	(30/346.53).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2002/10/03 11:28
-	56	(30/346.53).CCLS.	USOCR	2002/10/03 11:30
-	569	(76/104.1).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2002/10/03 12:54
-	385	(76/104.1).CCLS.	USOCR	2002/10/03 12:55
-	1	("5018274").PN.	USPAT	2002/10/03 12:57

-	35	30/346.53,346.54.ccls. and silicon	USPAT; US-PGPUB; EPO; JPO; DERWENT	2002/10/03 13:46
-	5	"5630275"	USPAT; US-PGPUB; EPO; JPO; DERWENT	2002/10/03 14:03
-	8	"5018274"	USPAT; US-PGPUB; EPO; JPO; DERWENT	2002/10/03 14:03
-	1	("0010969").PN.	USPAT; US-PGPUB	2002/10/07 14:55
-	78	"10969"	USPAT; US-PGPUB	2002/10/07 14:55
-	528	(30/50).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2002/10/07 15:00
-	105	30/\$.ccls. and etch\$3 and method	USPAT; US-PGPUB; EPO; JPO	2004/06/17 18:18
-	15	("3342754" "4534827" "5214011" "5222967" "5317938" "5380320" "5579583" "5683592" "5713133" "5728089" "5792137" "5842387" "5928161" "5944717" "5980518").PN.	USPAT	2004/06/17 18:16
-	41	30/\$.ccls. and etch\$3 and method	USOCR	2004/06/17 18:26
-	42	83/\$.ccls. and etch\$3 and method and crystal	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/06/17 18:33
-	5	83/\$.ccls. and etch\$3 and method and crystal	USOCR	2004/06/17 18:33